

Small Signal MOSFET 115 mAmps, 60 Volts N-Channel

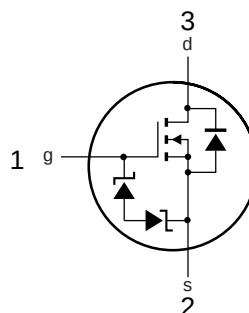
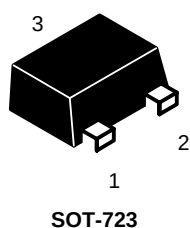
FEATURES:

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- ESD Protected : 2000V

APPLICATIONS:

- Load Switch

Circuit Diagram & Pin Configuration:



DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
2N7002EM3-S10T	PK	8000/Tape&Reel

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	60	V _{dc}
Drain Current – Continuous $T_C = 25^\circ\text{C}$ (Note 1.) – Pulse $t < 10\mu\text{s}$	I_D I_{DM}	± 115 ± 800	mAdc
Gate-Source Voltage – Continuous	V_{GS}	± 20	V _{dc}

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 2.) $T_A = 25^{\circ}\text{C}$ Derate above 25°C	P_D	150 1.2	mW mW/ $^{\circ}\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	833	$^{\circ}\text{C/W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^{\circ}\text{C}$

1. The Power Dissipation of the package may result in a lower continuous drain current.
2. FR-5 = 1.0 x 0.75 x 0.062 in.
3. Alumina = 0.4 x 0.3 x 0.025 in 99.5% alumina.

●Electrical characteristics ($T_A=25^{\circ}\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Gate-source leakage current	I_{GSS}	—	—	± 10	μA	$V_{GS}=\pm 20\text{V}, V_{DS}=0\text{V}$
Drain-source breakdown voltage	$V_{(BR)DSS}$	60	—	—	V	$I_D=10\mu\text{A}, V_{GS}=0\text{V}$
Zero gate voltage drain current	I_{DSS}	—	—	1	μA	$V_{DS}=60\text{V}, V_{GS}=0\text{V}$
Gate threshold voltage	$V_{GS(th)}$	1	1.85	2.5	V	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$
Drain-source on-state resistance	$R_{DS(on)}^*$	—	—	7.5	Ω	$I_D=0.5\text{A}, V_{GS}=10\text{V}$
		—	—	7.5		$I_D=0.05\text{A}, V_{GS}=5\text{V}$
Forward transfer admittance	$ Y_{fs} ^*$	80	—	—	mS	$V_{DS}=10\text{V}, I_D=0.2\text{A}$
Input capacitance	C_{iss}	—	25	50	pF	$V_{DS}=25\text{V}$
Output capacitance	C_{oss}	—	10	25	pF	$V_{GS}=0\text{V}$
Reverse transfer capacitance	C_{rss}	—	3.0	5.0	pF	$f=1\text{MHz}$
Turn-on delay time	$t_{d(on)}^*$	—	12	20	ns	$I_D=200\text{mA}, V_{DD}=30\text{V}$
Turn-off delay time	$t_{d(off)}^*$	—	20	30	ns	$V_{GS}=10\text{V}, R_L=150\Omega, R_{GS}=10\Omega$

* $P_w \leq 300\mu\text{s}$, Duty cycle $\leq 1\%$

●Electrical characteristic curves

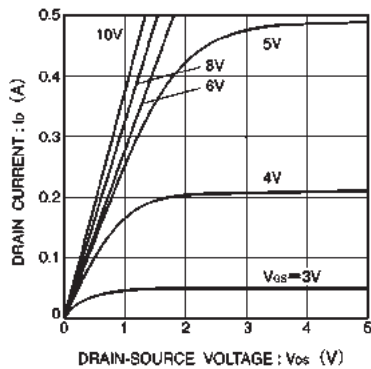


Fig.1 Typical output characteristics

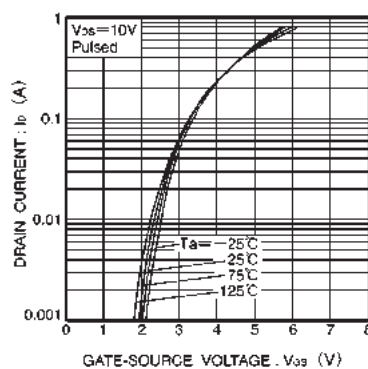


Fig.2 Typical transfer characteristics

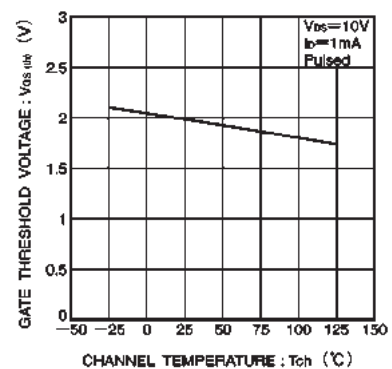


Fig.3 Gate threshold voltage vs. channel temperature

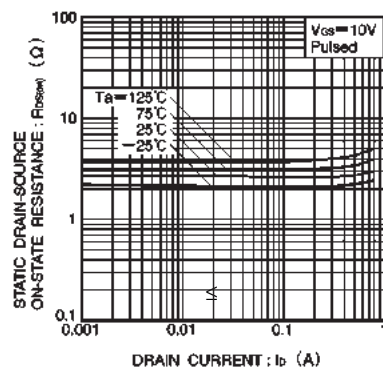


Fig.4 Static drain-source on-state resistance vs. drain current (I)

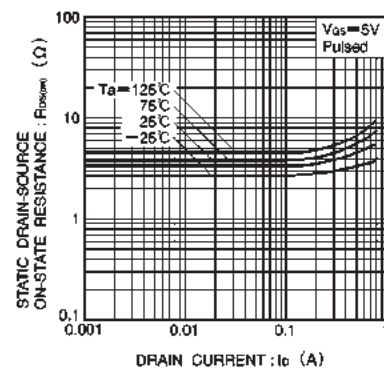


Fig.5 Static drain-source on-state resistance vs. drain current (II)

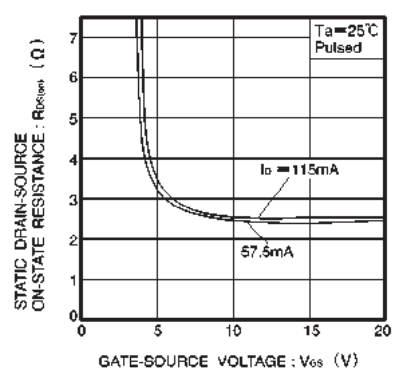


Fig.6 Static drain-source on-state resistance vs. gate-source voltage

●Electrical characteristic curves (continues)

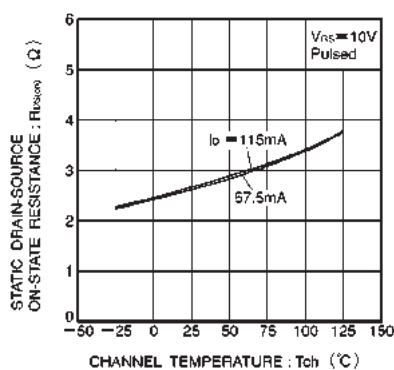


Fig.7 Static drain-source on-state resistance vs. channel temperature

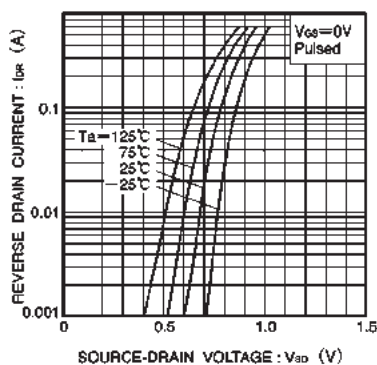


Fig.8 Reverse drain current vs. source-drain voltage (I)

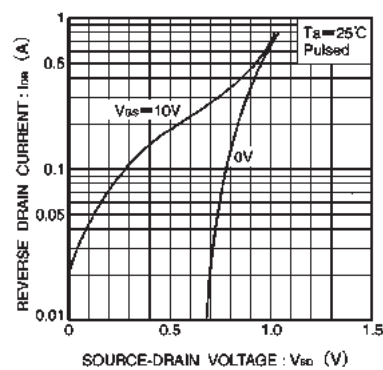


Fig.9 Reverse drain current vs. source-drain voltage (II)

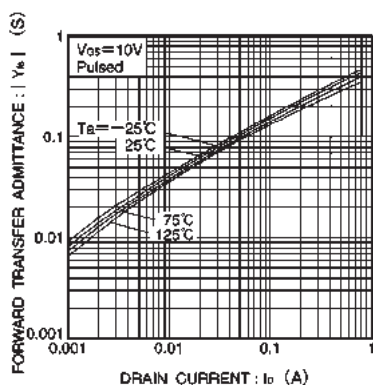


Fig.10 Forward transfer admittance vs. drain current

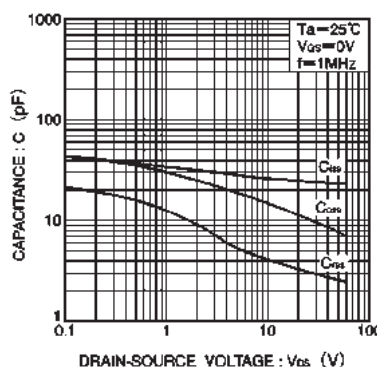


Fig.11 Typical capacitance vs. drain-source voltage

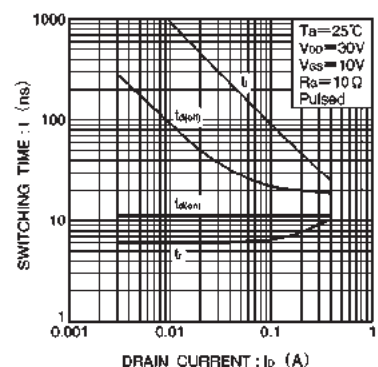


Fig.12 Switching characteristics
(See Figures 13 and 14 for the measurement circuit and resultant waveforms)

●Switching characteristics measurement circuit

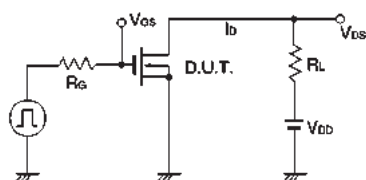


Fig.13 Switching time measurement circuit

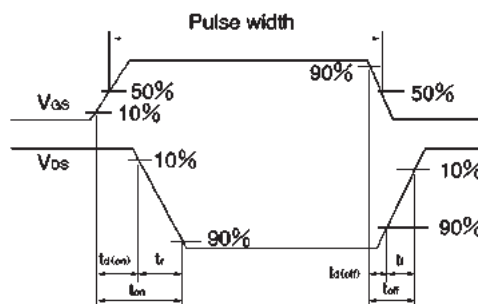
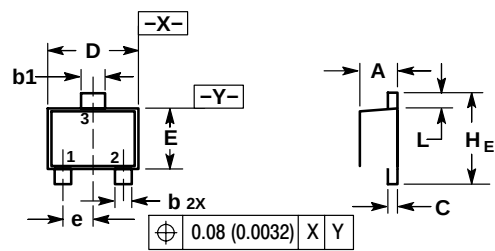


Fig.14 Switching time waveforms

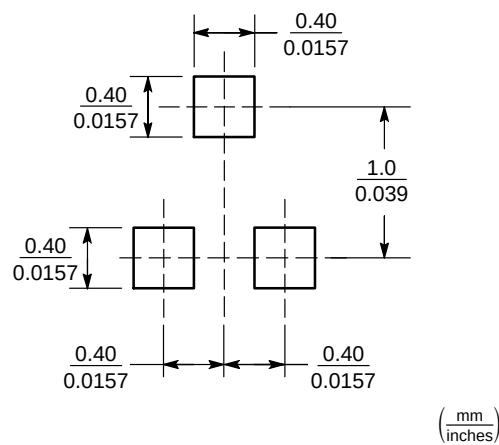
SOT-723



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
b	0.15	0.20	0.27	0.0059	0.0079	0.0106
b1	0.25	0.3	0.35	0.010	0.012	0.014
C	0.07	0.12	0.17	0.0028	0.0047	0.0067
D	1.15	1.20	1.25	0.045	0.047	0.049
E	0.75	0.80	0.85	0.03	0.032	0.034
e	0.40 BSC			0.016 BSC		
H E	1.15	1.20	1.25	0.045	0.047	0.049
L	0.15	0.20	0.25	0.0059	0.0079	0.0098

SOLDERING FOOTPRINT



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